

Standard Rectifier Module

$V_{RRM} = 1600\text{ V}$
 $I_{FAV} = 608\text{ A}$
 $V_F = 1.01\text{ V}$

Single Diode

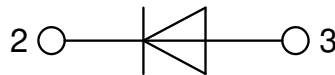
Part number

MDO600-16N1



Backside: isolated

 E72873



Features / Advantages:

- Planar passivated chips
- Very low leakage current
- Very low forward voltage drop
- Improved thermal behaviour

Applications:

- Diode for main rectification
- For single and three phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Package: Y1

- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Base plate: Copper internally DCB isolated
- Advanced power cycling

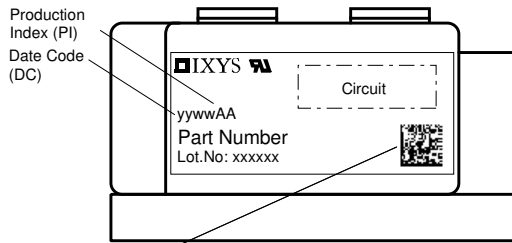
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Rectifier				Ratings			
Symbol	Definition	Conditions		min.	typ.	max.	Unit
V_{RSM}	max. non-repetitive reverse blocking voltage					1700	V
V_{RRM}	max. repetitive reverse blocking voltage					1600	V
I_R	reverse current	$V_R = 1600$ V		$T_{VJ} = 25^\circ\text{C}$		1	mA
		$V_R = 1600$ V		$T_{VJ} = 140^\circ\text{C}$		30	mA
V_F	forward voltage drop	$I_F = 600$ A		$T_{VJ} = 25^\circ\text{C}$		1.12	V
		$I_F = 1200$ A				1.30	V
		$I_F = 600$ A		$T_{VJ} = 125^\circ\text{C}$		1.01	V
		$I_F = 1200$ A				1.23	V
I_{FAV}	average forward current	$T_C = 85^\circ\text{C}$		$T_{VJ} = 140^\circ\text{C}$		608	A
		180° sine	d = 0.5				
V_{FO}	threshold voltage	} for power loss calculation only		$T_{VJ} = 140^\circ\text{C}$		0.76	V
r_F	slope resistance					0.32	mΩ
R_{thJC}	thermal resistance junction to case					0.072	K/W
R_{thCH}	thermal resistance case to heatsink				0.024		K/W
P_{tot}	total power dissipation			$T_C = 25^\circ\text{C}$		1600	W
I_{FSM}	max. forward surge current	t = 10 ms; (50 Hz), sine		$T_{VJ} = 45^\circ\text{C}$		15.0	kA
		t = 8,3 ms; (60 Hz), sine		$V_R = 0$ V		16.2	kA
		t = 10 ms; (50 Hz), sine		$T_{VJ} = 140^\circ\text{C}$		12.8	kA
		t = 8,3 ms; (60 Hz), sine		$V_R = 0$ V		13.8	kA
I^2t	value for fusing	t = 10 ms; (50 Hz), sine		$T_{VJ} = 45^\circ\text{C}$		1.13	MA ² s
		t = 8,3 ms; (60 Hz), sine		$V_R = 0$ V		1.09	MA ² s
		t = 10 ms; (50 Hz), sine		$T_{VJ} = 140^\circ\text{C}$		812.8	kA ² s
		t = 8,3 ms; (60 Hz), sine		$V_R = 0$ V		788.8	kA ² s
C_J	junction capacitance	$V_R = 400$ V; f = 1 MHz		$T_{VJ} = 25^\circ\text{C}$		762	pF



Package Y1			Ratings			
Symbol	Definition	Conditions	min.	typ.	max.	Unit
I_{RMS}	RMS current	per terminal			600	A
T_{VJ}	virtual junction temperature		-40		140	°C
T_{op}	operation temperature		-40		125	°C
T_{stg}	storage temperature		-40		125	°C
Weight				650		g
M_D	mounting torque		4.5		7	Nm
M_T	terminal torque		11		13	Nm
$d_{Spp/App}$	creepage distance on surface striking distance through air	terminal to terminal	16.0			mm
$d_{Spb/Apb}$		terminal to backside	25.0			mm
V_{ISOL}	isolation voltage	t = 1 second	3600			V
		t = 1 minute	3000			V



Data Matrix: part no. (1-19), DC + PI (20-25), lot.no.# (26-31), blank (32), serial no.# (33-36)

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	MDO600-16N1	MDO600-16N1	Box	2	509707

Equivalent Circuits for Simulation

* on die level

$T_{VJ} = 140^{\circ}C$

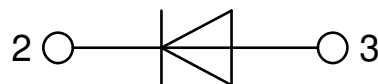
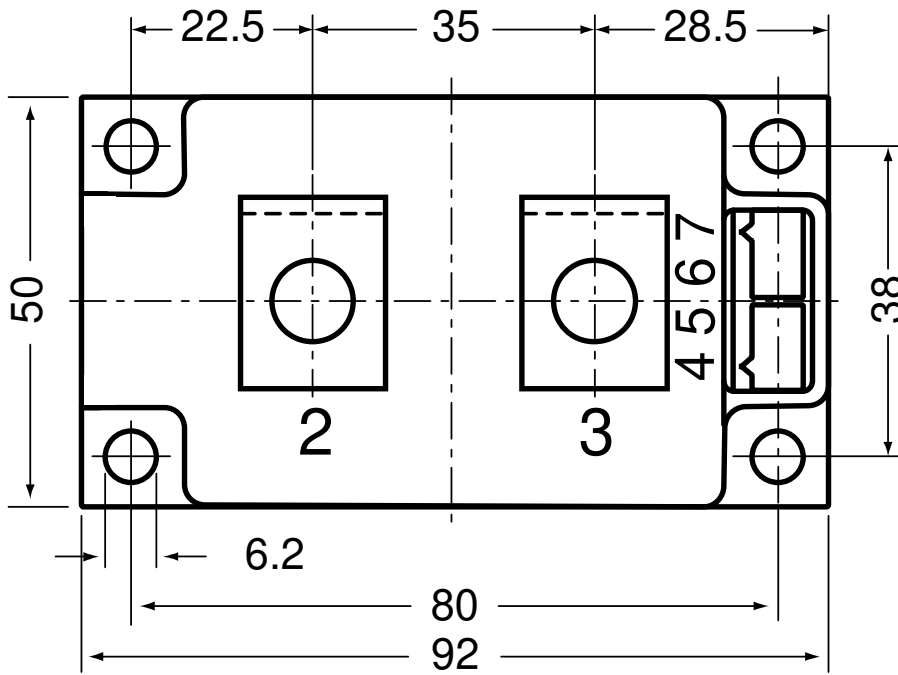
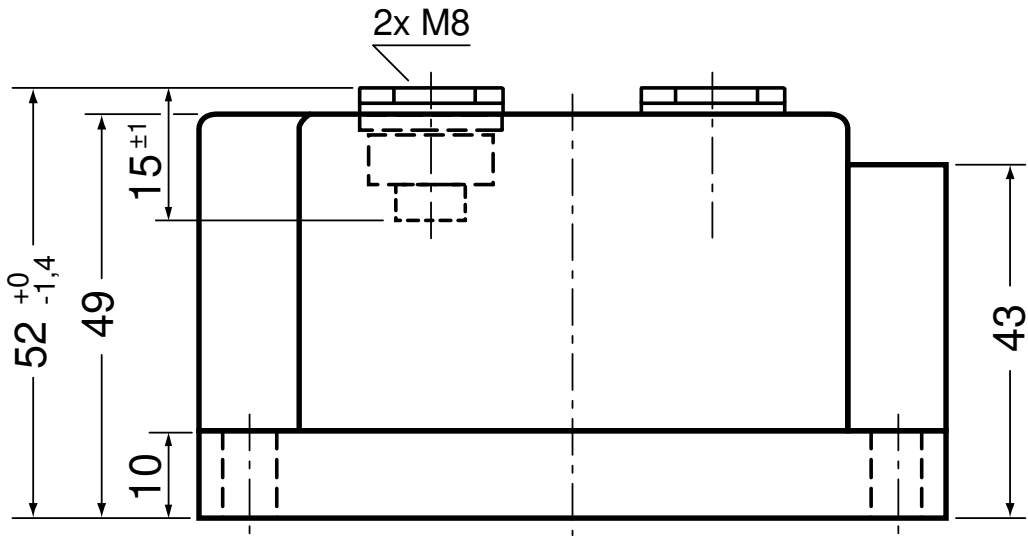


Rectifier

$V_{0\ max}$	threshold voltage	0.76	V
$R_{0\ max}$	slope resistance *	0.13	mΩ



Outlines Y1



Rectifier

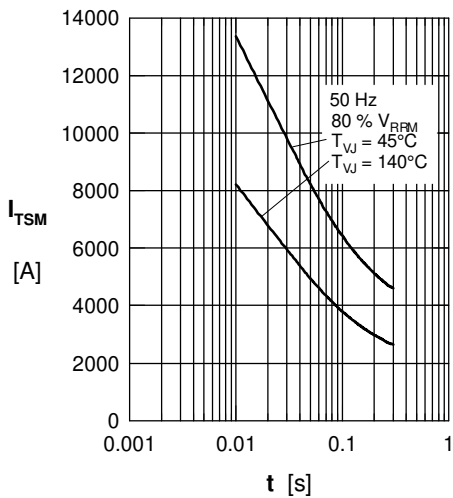


Fig. 1 Surge overload current
 I_{FSM} : Crest value, t: duration

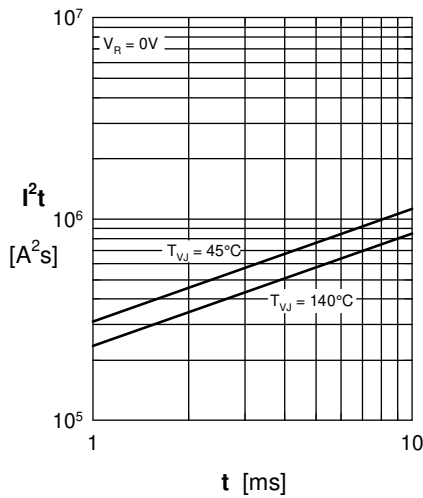


Fig. 2 I^2t versus time (1-10 ms)

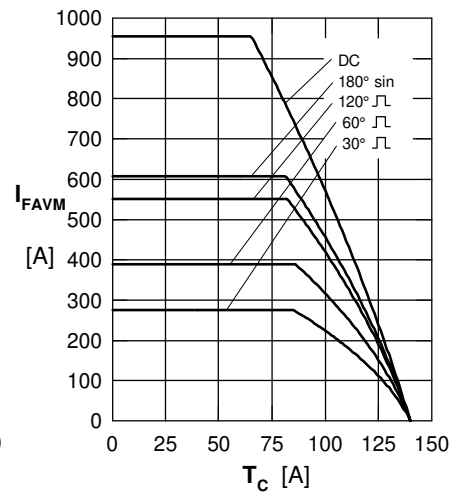


Fig. 3 Max. forward current at case temperature

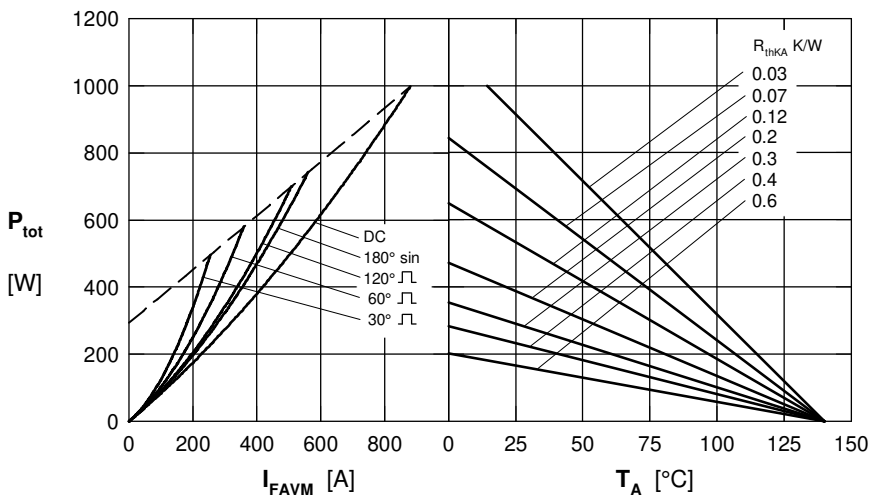


Fig. 4 Power dissipation vs. forward current and ambient temperature

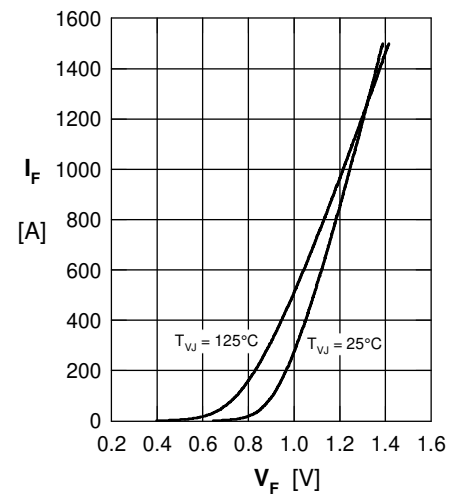


Fig. 5 Forward current I_F vs. V_F

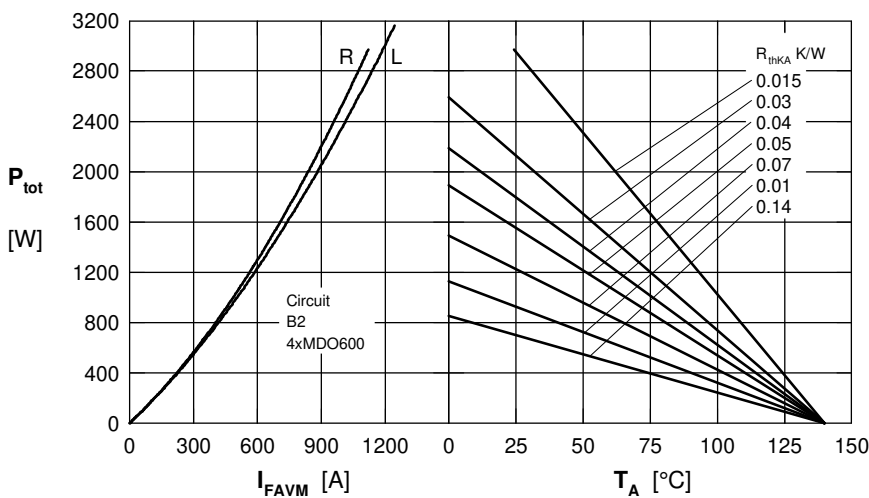


Fig. 6 Single phase rectifier bridge: Power dissipation vs. direct output current and ambient temperature R = resistive load, L = inductive load



Rectifier

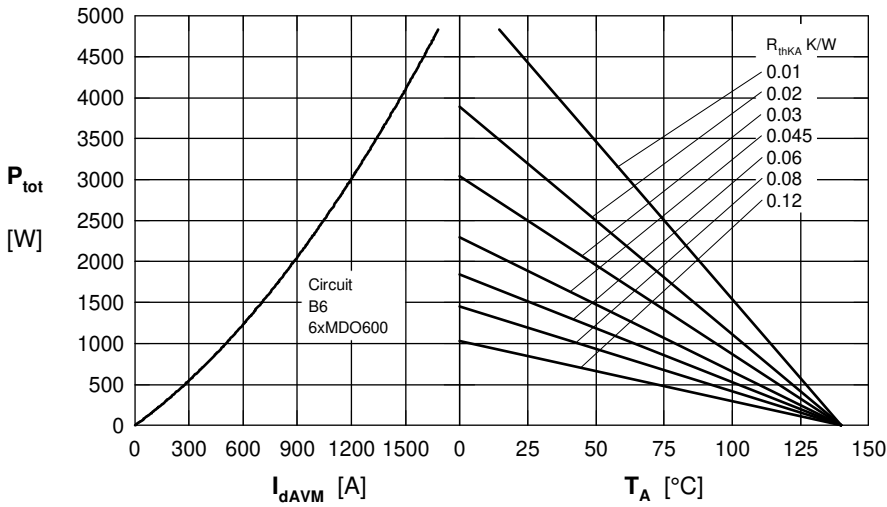


Fig. 7 Three phase rectifier bridge: Power dissipation versus direct output current and ambient temperature

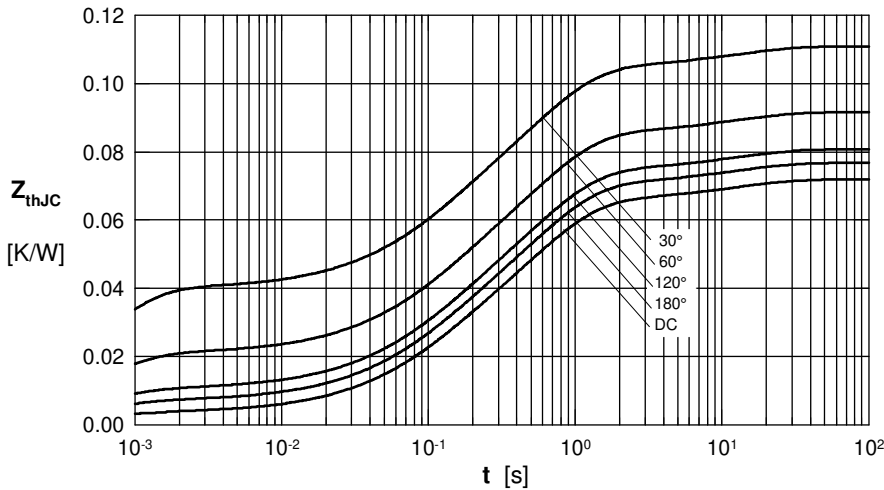


Fig. 8 Transient thermal impedance junction to case

R_{thJC} for various conduction angles d:

d	R_{thJC} (K/W)
DC	0.072
180°	0.0768
120°	0.081
60°	0.092
30°	0.111

Constants for Z_{thJC} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.0035	0.0054
2	0.0186	0.098
3	0.0432	0.54
4	0.0067	12

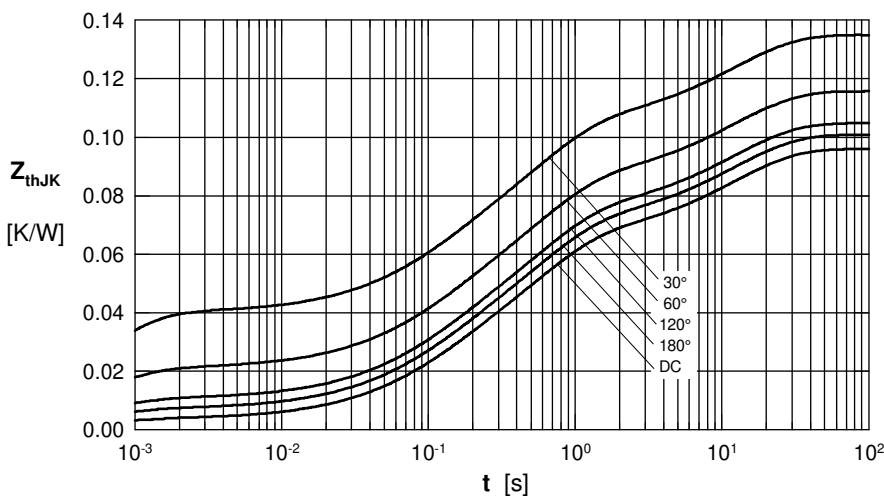


Fig. 9 Transient thermal impedance junction to heatsink

R_{thJK} for various conduction angles d:

d	R_{thJK} (K/W)
DC	0.096
180°C	0.1
120°C	0.105
60°C	0.116
30°C	0.135

Constants for Z_{thJK} calculation:

i	R_{thi} (K/W)	t_i (s)
1	0.0035	0.0054
2	0.0186	0.098
3	0.0432	0.54
4	0.067	12
5	0.024	12